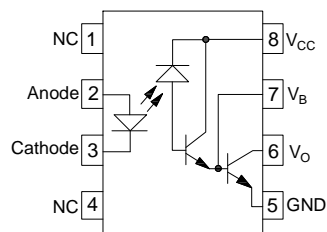
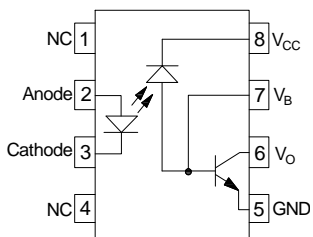




The products are 1MBd high-speed opto-couplers. The device is a small-outline coupler suitable for surface-mount assembly. It consists of a high-output-power infrared LED optically coupled to a high-speed photodiode-transistor chip. It is housed in a plastic DIP8 package with different lead forming options package and guarantees a creepage distance of 5 mm, a clearance of 5 mm and an insulation thickness of 0.4 mm. Therefore, it meets the reinforced insulation class requirements of international safety standards. The products are widely used in programmable controllers, industrial inverters and switching power supplies.

- High isolation 5000 VRMS
- High speed – 1MBd typical
- Operating temperature range -55°C to 110°C
- REACH & RoHS compliance
- HBM: H3A; MM: M4; CDM: C3
- CQC approved
- VDE approved
- UL approved



Note: VB Default NC

LED	Output
ON	L
OFF	H



(Temperature=25°C)

Input	Forward Current	$I_F$	50	mA
	Peak Forward Current	$I_{FP}$	1	A
	Reverse Voltage	$V_R$	6	V
	Input Power Dissipation	$P_D$	100	mW
Output	Supply Voltage	$V_{CC}$	35	V
	Output Voltage	$V_O$	20	V
	Output Current	$I_O$	8	mA
	Output Power Dissipation	$P_O$	100	mW
Total Power Dissipation		$P_{tot}$	200	mW
Isolation Voltage		$V_{iso}$	5000	Vrms
Operating Temperature		$T_{opr}$	-55~110	
Junction Temperature		$T_j$	125	
Storage Temperature		$T_{stg}$	-55~125	
Soldering Temperature		$T_{sol}$	260	

: 100μs pulse, 100Hz frequency

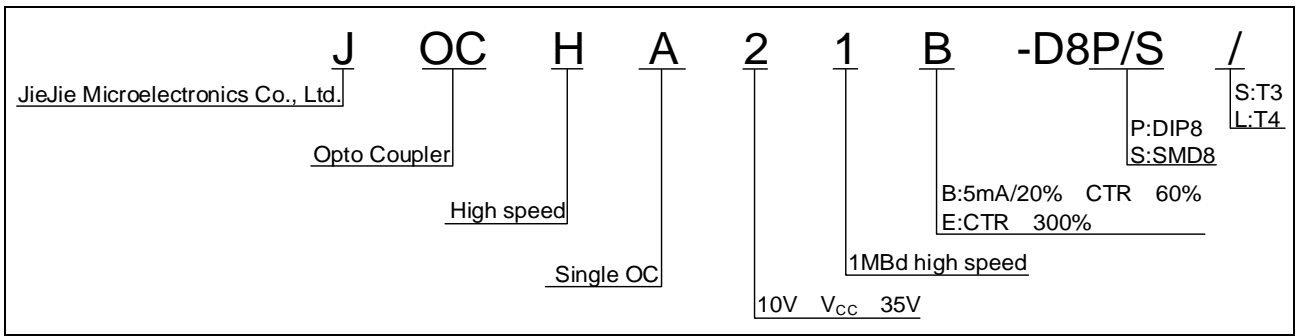
: AC for 1minute, R.H.=40~60%

(Temperature=25°C)

Input	Forward Voltage	$V_F$	$I_F=10mA$	-	1.35	1.6	V	
	Reverse Current	$I_R$	$V_R=6V$	-	-	1	μA	
	Input Capacitance	$C_{in}$	$V=0, f=1MHz$	-	60	-	pF	
Output	Current transfer ratio	CTR	B	$I_F=16mA, V_{CC}=4.5V,$ $V_O=0.4V$	20	-	60	%
			E		300	-	-	
	High Level Output Current	$I_{OH}$	$I_F=0mA, V_{CC}=5.5V,$ $V_O=5.5V$	-	3	500	nA	
			$I_F=0mA, V_{CC}=15V,$ $V_O=15V$	-	-	50	μA	
	Low Level Supply Current	$I_{CCL}$	$V_O=Open,$ $V_{CC}=15V,$ $I_F=16mA$	-	0.5	0.8	mA	
High Level Supply Current	$I_{CCH}$	$V_O=Open,$ $V_{CC}=15V,$ $I_F=0mA$	-	0.01	2	μA		

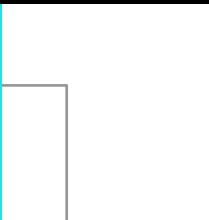
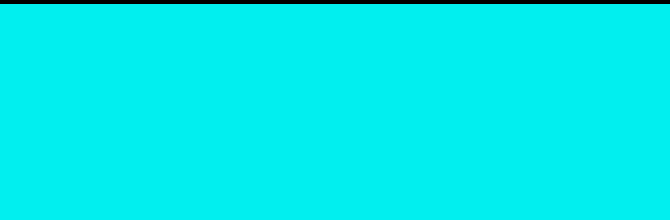
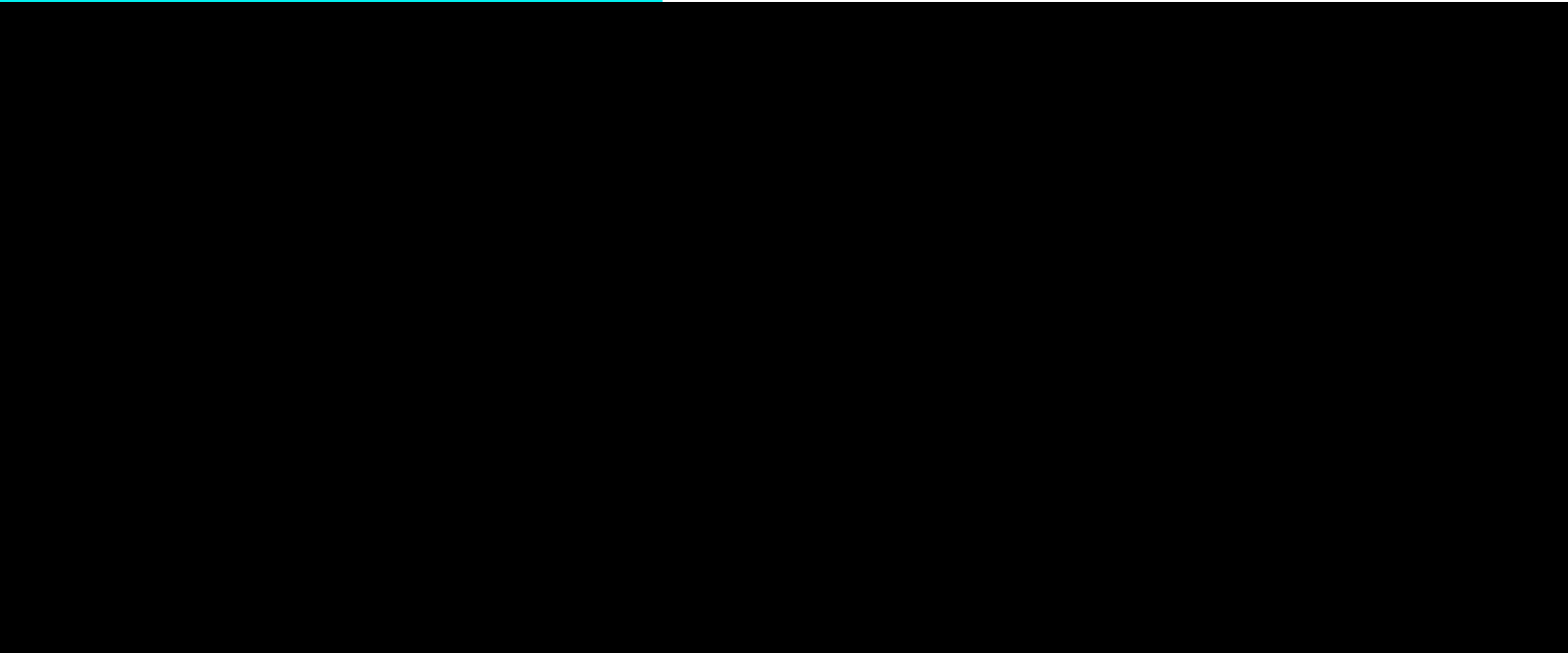


	Logic Low Output Voltage	$V_{OL}$	$I_F=16\text{mA}$ , $I_O=2.4\text{mA}$ , $V_{CC}=4.5\text{V}$	-	-	0.4	V
	Isolation Resistance	$R_{ISO}$	DC500V 40~60%R.H.	$10^{12}$	$10^{14}$	-	
	Floating Capacitance	$C_{IO}$	$V=0$ , $f=1\text{MHz}$	-	0.8	-	pF
Switching Characteristics	Propagation Delay Time to Logic Low	TPHL	$I_F=0$ 16mA, $R_L=1.9\text{k}$ , $V_{CC}=5\text{V}$	-	-	0.8	$\mu\text{s}$
	Propagation Delay Time to Logic High	TPLH	$I_F=16$ 0mA, $R_L=1.9\text{k}$ , $V_{CC}=5\text{V}$	-	-	0.8	$\mu\text{s}$
	Common Mode Transient Immunity at Logic High	$CM_H$	$I_F=0\text{mA}$ , $V_{CM}=400\text{Vpp}$ , $R_L=4.1\text{k}$	15	20	-	kV/ $\mu\text{s}$
	Common Mode Transient Immunity at Logic Low	$CM_L$	$I_F=16\text{mA}$ , $V_{CM}=400\text{Vpp}$ , $R_L=4.1\text{k}$	-15	-20	-	kV/ $\mu\text{s}$



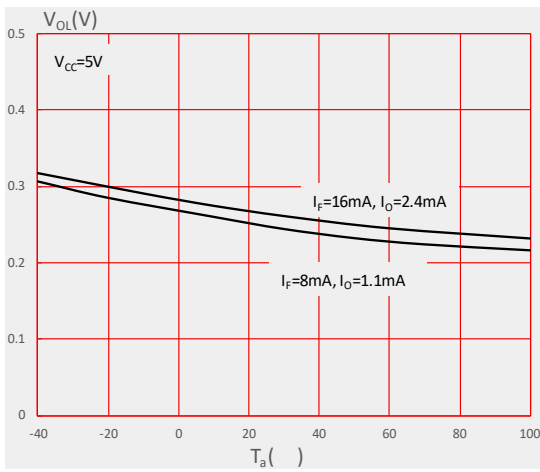
DIP	50 Units/Tube
SMD	1200 Units/Reel



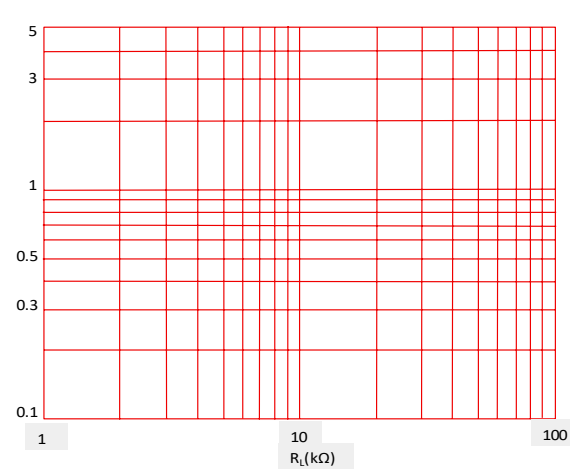




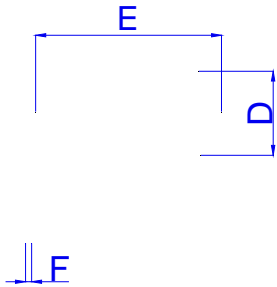
### Low Level Output Voltage vs. Ambient Temperature



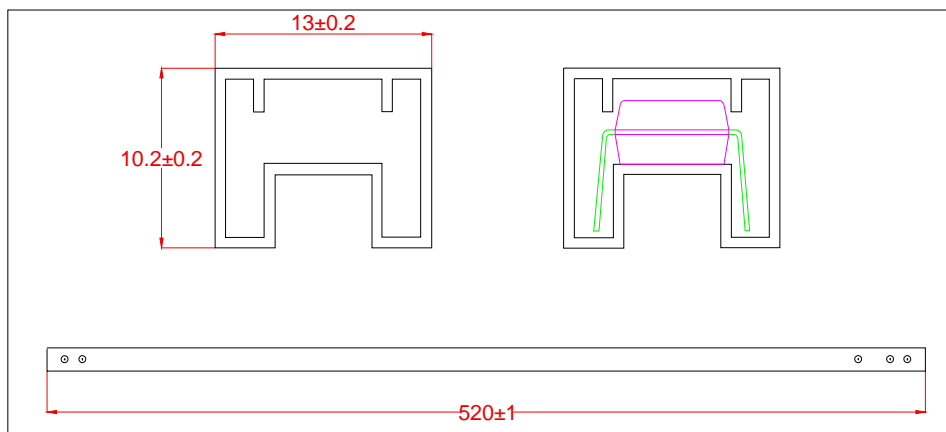
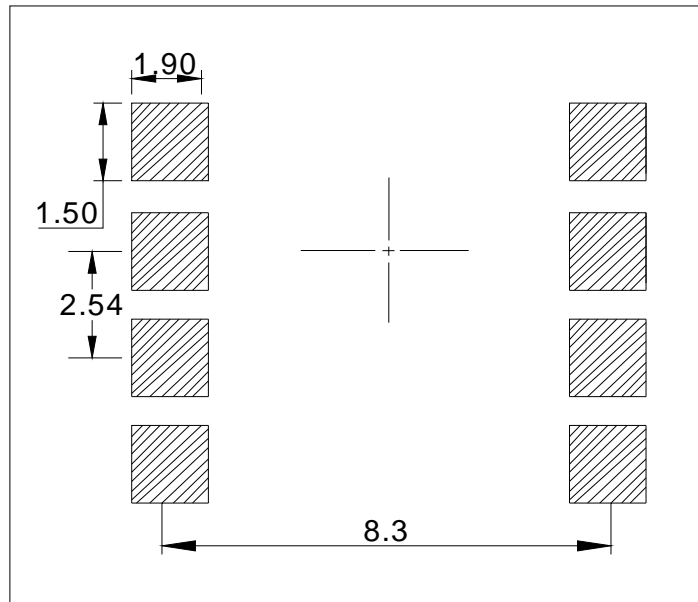
### Propagation Delay vs. Load Resistance

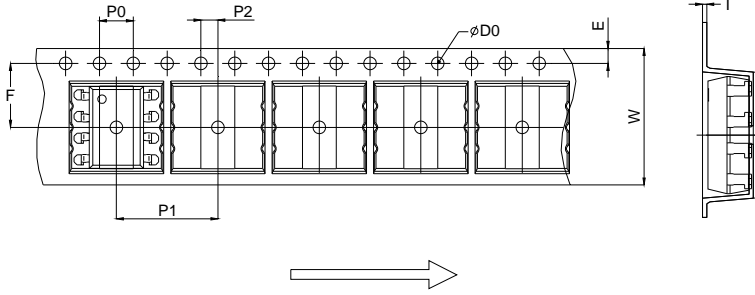




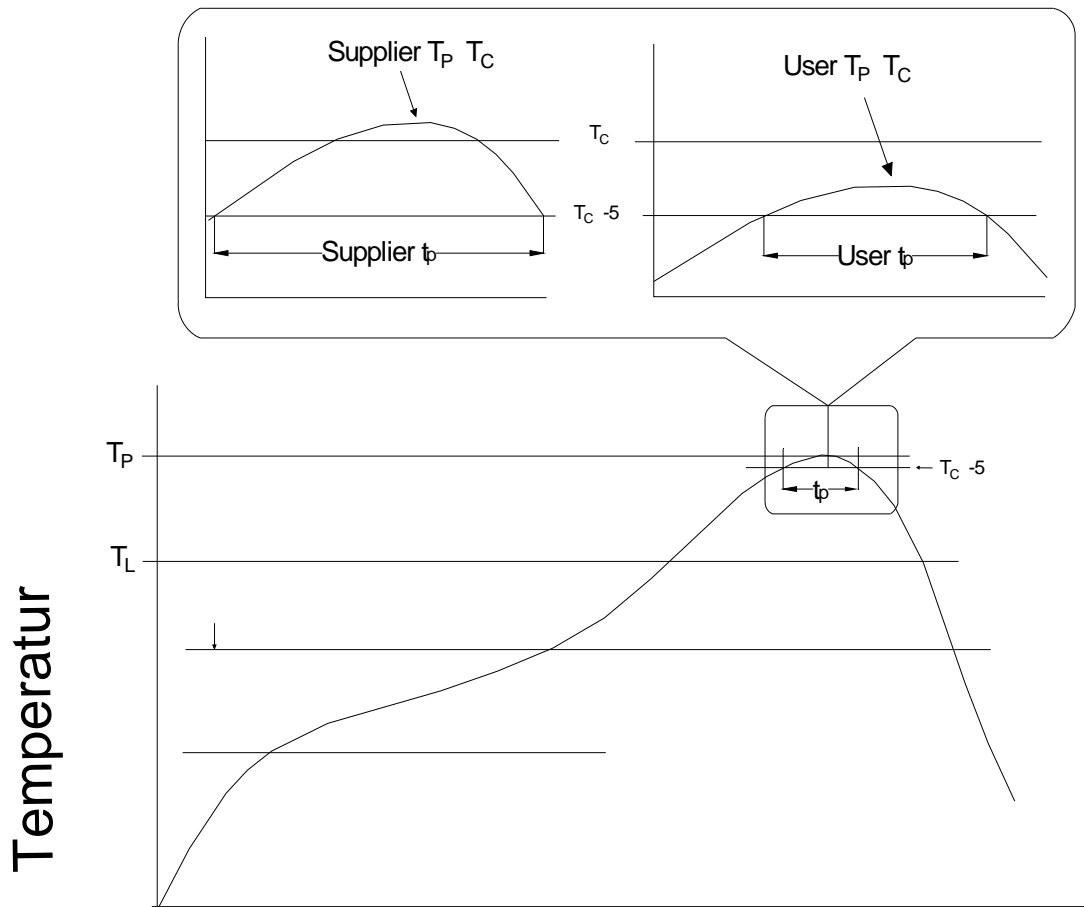


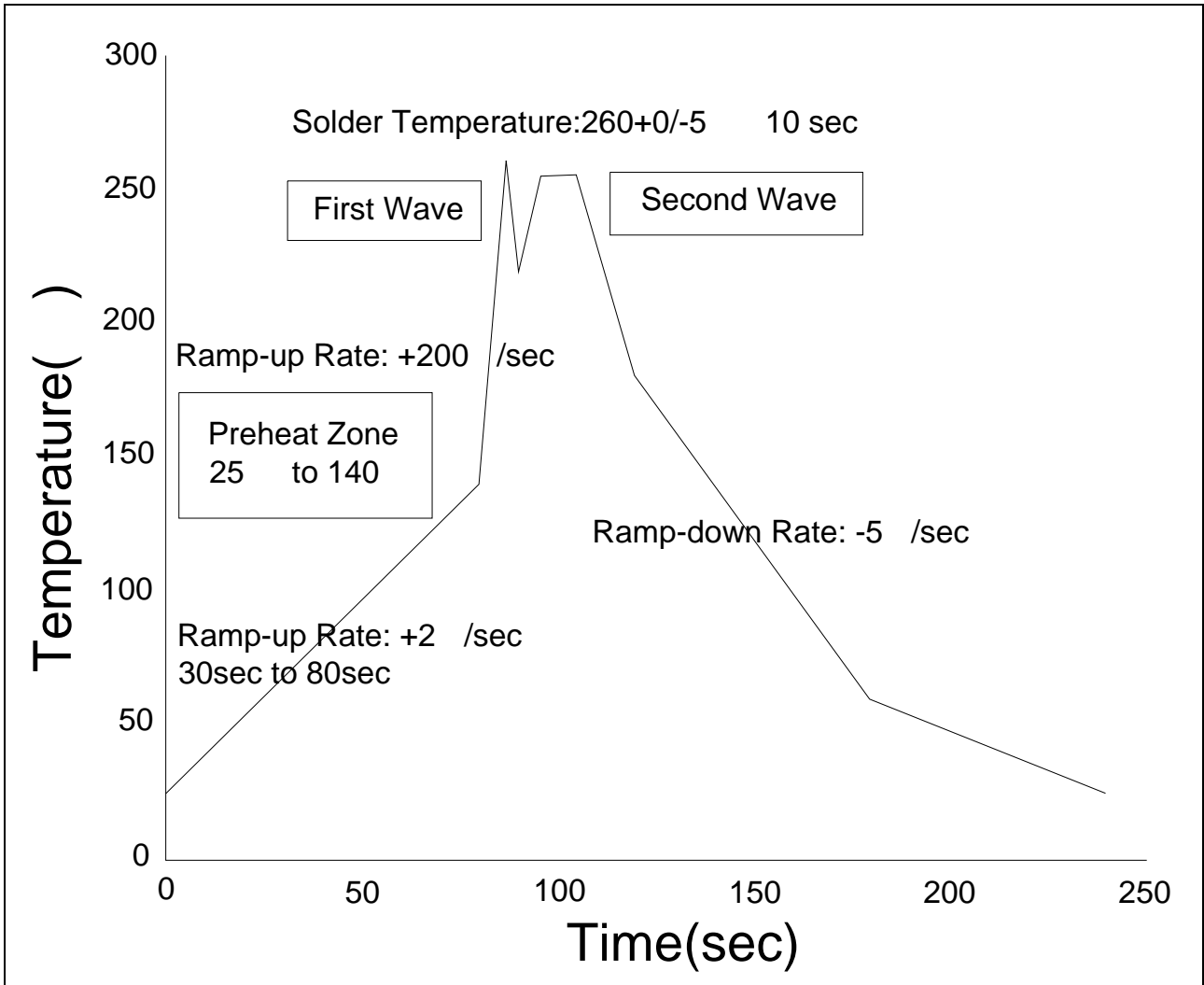
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A						
B						
C	7.15		8.95	0.281		0.352
D						
E						
F						
G						
H						
I						
J						





Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
D0		1.50	1.60		0.059	0.063
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	11.90	12.00	12.10	0.469	0.472	0.476
P2	1.90	2.00	2.10	0.075	0.079	0.083
E	1.65	1.75	1.85	0.065	0.069	0.073
F	7.40	7.50	7.60	0.291	0.295	0.299
T	0.35	0.40	0.45	0.014	0.016	0.018
W	15.90	16.00	16.20	0.626	0.630	0.638





Soldering Temperature	360± 5
Soldering Time	3s max.

